

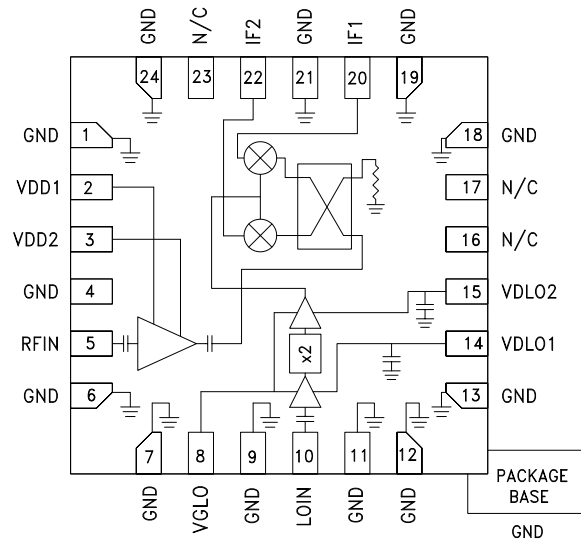


Typical Applications

The HMC1065LP4E is ideal for:

- Point-to-Point and Point-to-Multi-Point Radios
- Satellite Communications
- Sensors

Functional Diagram



GaAs MMIC I/Q DOWNCONVERTER 27 - 34 GHz

Features

Conversion Gain: 13 dB

Image Rejection: 17 dBc

Input Third-Order Intercept (IP3): -2 dBm

LO Drive Range: -4 dBm to +4 dBm

24 Lead 4 mm x 4 mm SMT Package

General Description

The HMC1065LP4E is a compact GaAs MMIC Image Reject Low Noise Converter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 13 dB with 17 dBc of image rejection and 2 dBm of Input IP3. The HMC1065LP4E utilizes an RF LNA followed by an I/Q mixer which is driven by an active x2 multiplier. IF1 and IF2 mixer outputs are provided and an external 90° hybrid is needed to select the required sideband. The I/Q mixer topology reduces the need for filtering of the unwanted sideband. The HMC1065LP4E is a much smaller alternative to hybrid style image reject downconverter assemblies and it eliminates the need for wire bonding by allowing the use of surface mount manufacturing techniques.

Electrical Specifications,

$T_A = +25^\circ\text{C}$, $IF = 2000\text{ MHz}$, $LO = +2\text{ dBm}$, $VDLO1 = VDLO2 = 3\text{ V}$, $VDD1 = VDD2 = 3\text{ V}$, USB [1]

Parameter	Min.	Typ.	Max.	Units
RF Frequency Range	27		34	GHz
LO Frequency Range	11.5		19	GHz
IF Frequency Range	DC		4	GHz
LO Drive Range	-4		+4	dBm
Conversion Gain	9	12		dB
Noise Figure		3		dB
Image Rejection	12	17		dBc
Input Power for 1 dB Compression (P1dB)		-9		dBm
Input Third-Order Intercept (IIP3)		-2		dBm
Output Third-Order Intercept (OIP3)		14		dBm
2x LO / RF Isolation	35	45		dB
2x LO / IF Isolation		20		dB
Amplitude Balance [2]		-1		dB
Phase Balance [2]		7		deg
Supply Current (IDLO) [3]		150		mA
Supply Current (IDD)		90		mA

[1] All measurements performed with upper sideband selected and external 90° hybrid at the IF ports, unless otherwise noted.

[2] Data taken without external 90° hybrid, IF = 1000 MHz.

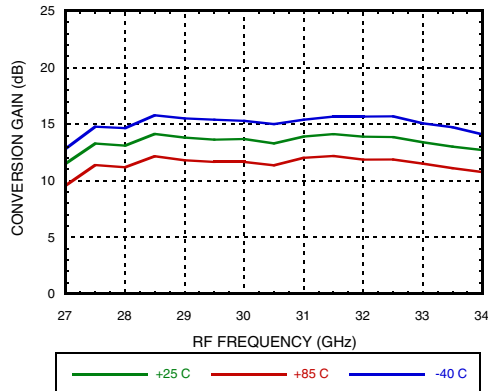
[3] Adjust VGLO1 and VGLO2 between -2 V and 0 V to achieve total quiescent current (IDLO1 + IDLO2) = 150 mA.



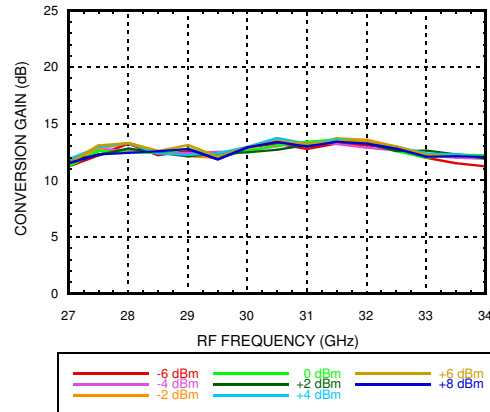
**GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

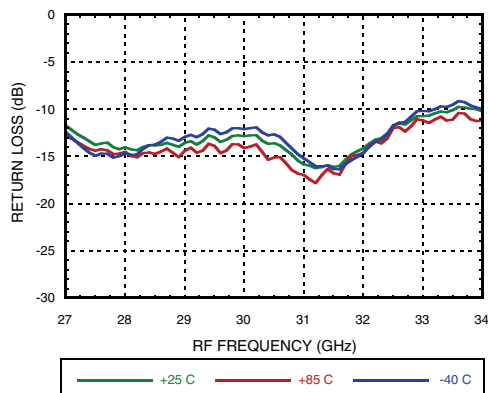
Conversion Gain vs. Temperature, USB



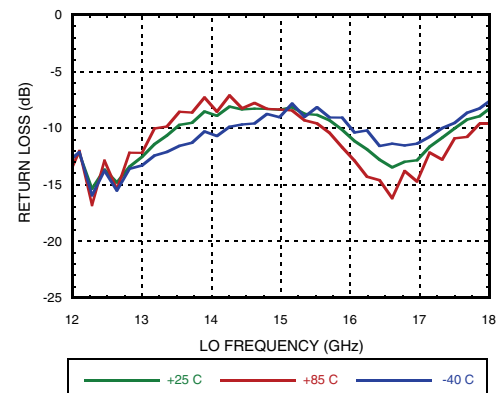
Conversion Gain vs. LO Drive, USB



RF Return Loss vs. Temperature



LO Return Loss vs. Temperature



IF Return Loss ^[1]

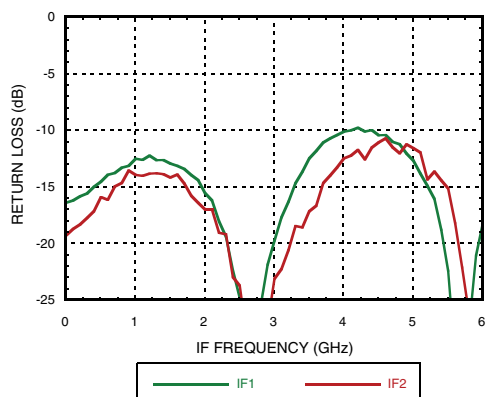
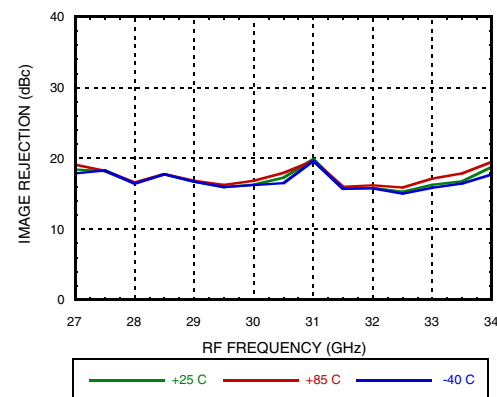


Image Rejection vs. Temperature, USB



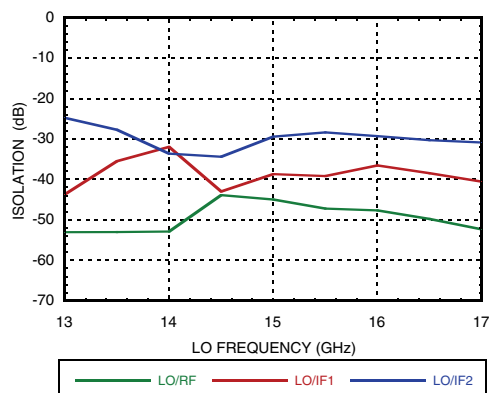
[1] Data taken without external IF 90° hybrid



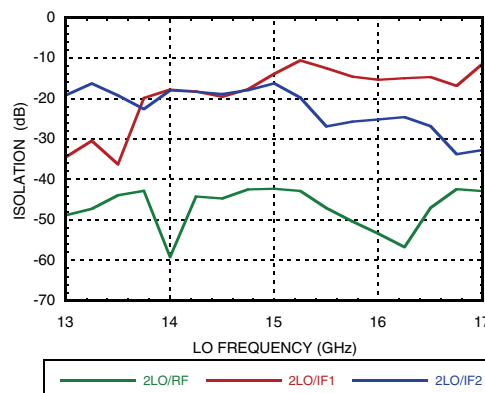
GaAs MMIC I/Q DOWNCONVERTER 27 - 34 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

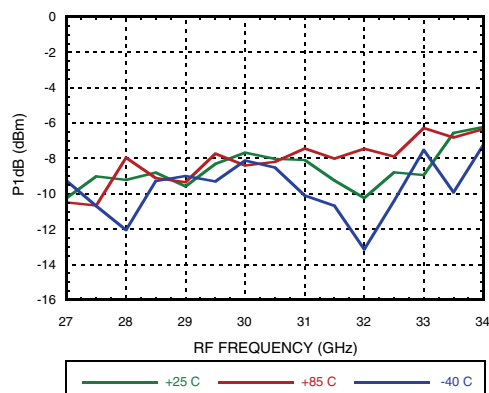
LO Isolation [1]



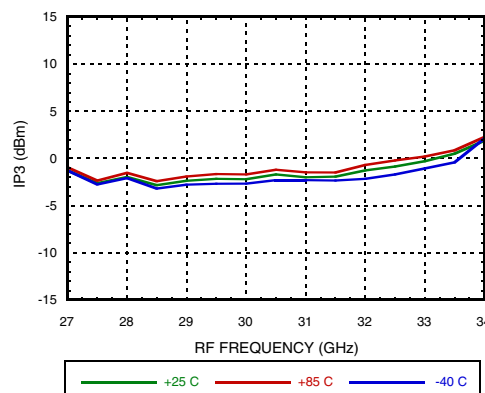
2x LO Isolation [1]



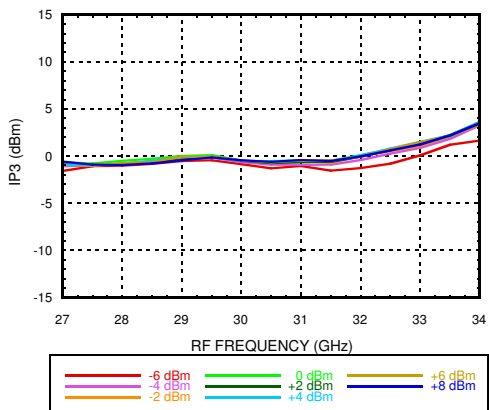
Input P1dB vs. Temperature, USB



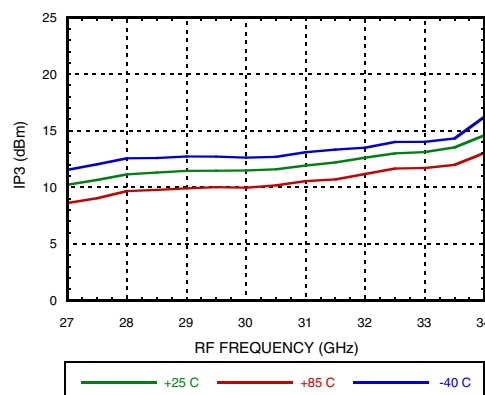
Input IP3 vs. Temperature, USB



Input IP3 vs. LO Drive, USB



Output IP3 vs. Temperature, USB



[1] Data taken without external IF 90° hybrid

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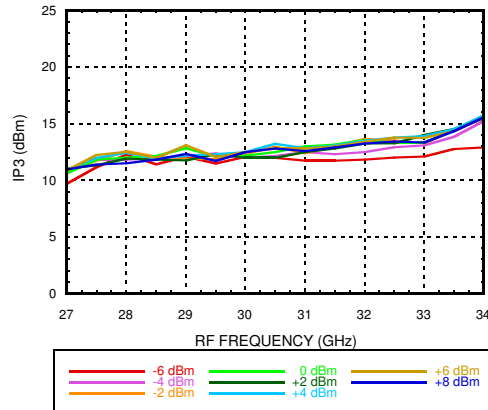
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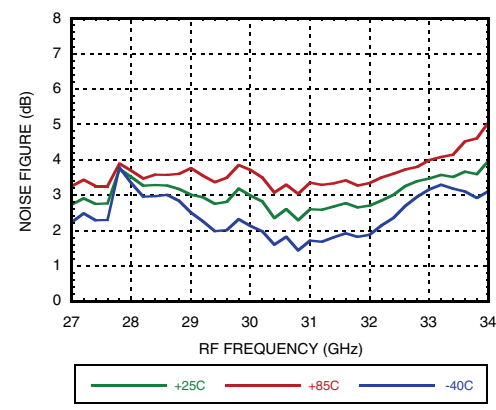
GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

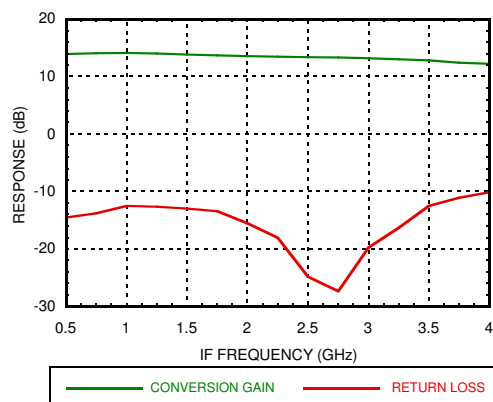
Output IP3 vs. LO Drive, USB



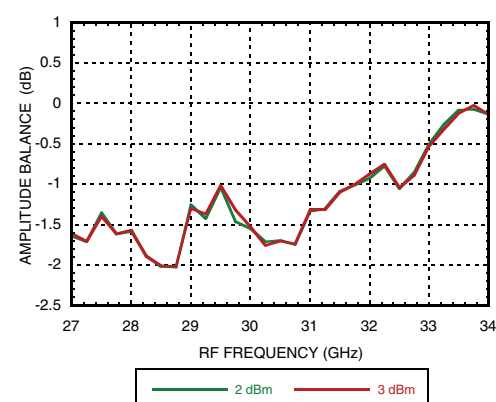
Noise Figure vs. Temperature, USB



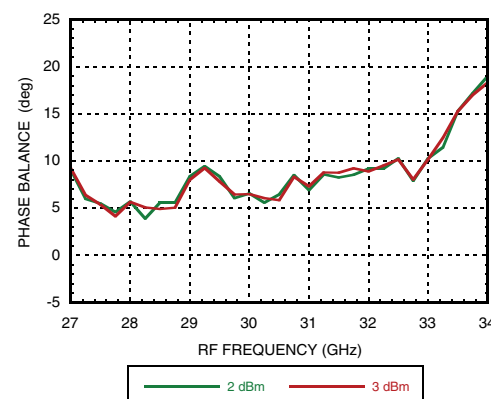
IF Bandwidth ^[1]



Amplitude Balance vs. LO Drive ^{[1] [2]}



Phase Balance vs. LO Drive ^{[1] [2]}



[1] Data taken without external 90° hybrid.

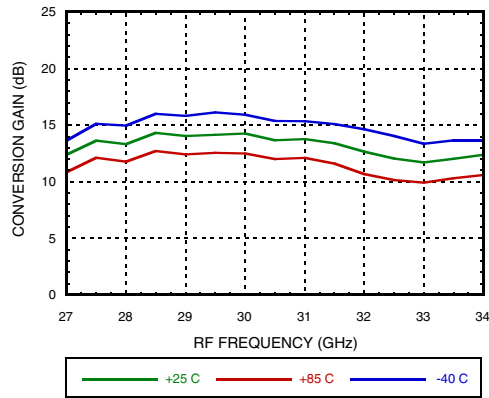
[2] Data taken with IF = 1000MHz.



**GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

Conversion Gain vs. Temperature, LSB



Conversion Gain vs. LO Drive, LSB

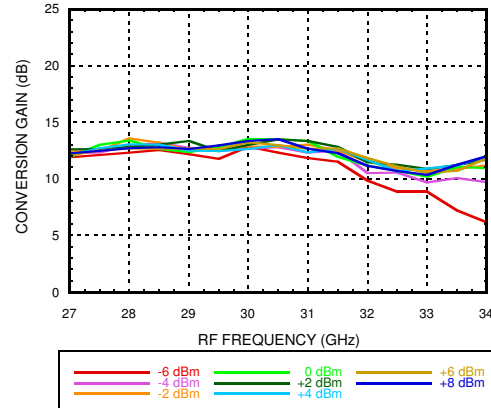
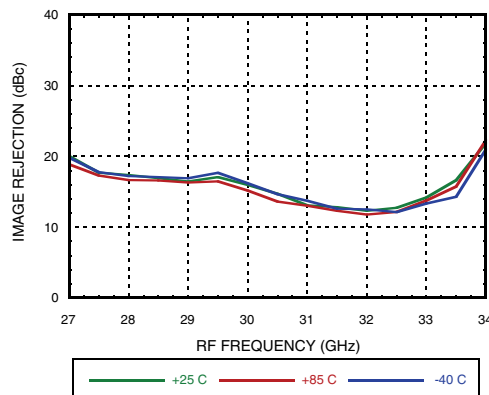
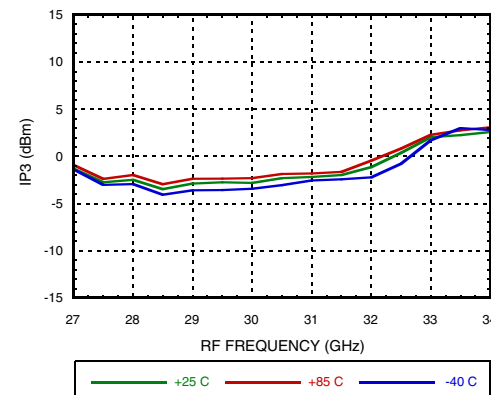


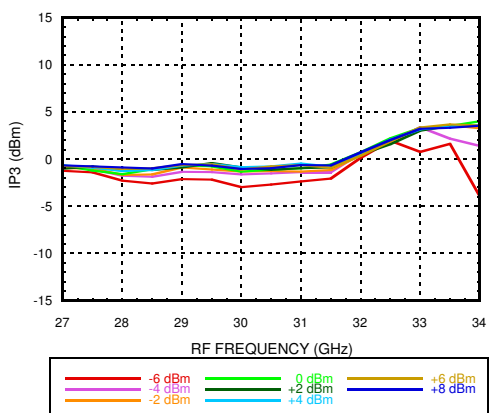
Image Rejection vs. Temperature, LSB



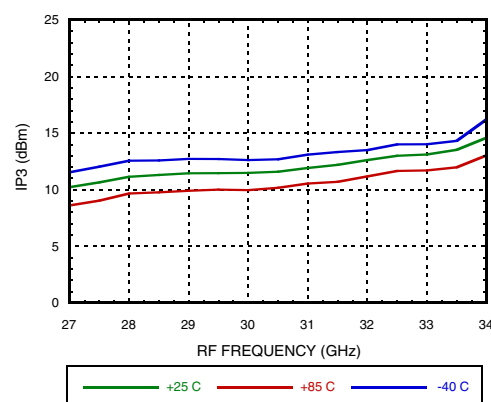
Input IP3 vs. Temperature, LSB



Input IP3 vs. LO Drive, LSB



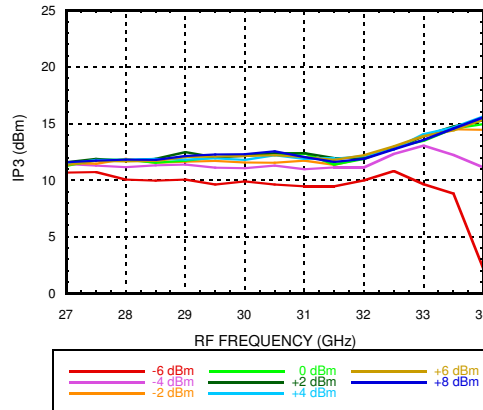
Output IP3 vs. Temperature, LSB





GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz
Output IP3 vs. LO Drive, LSB



Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz
Conversion Gain vs. Temperature, USB **Conversion Gain vs. LO Drive, USB**

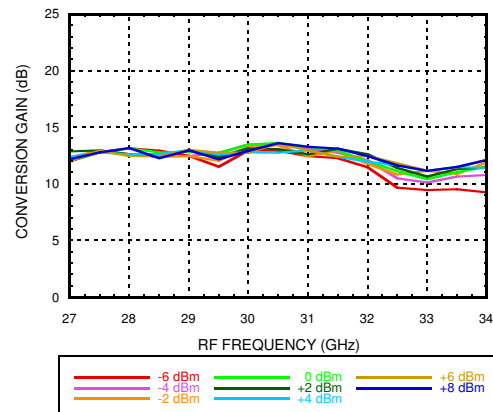
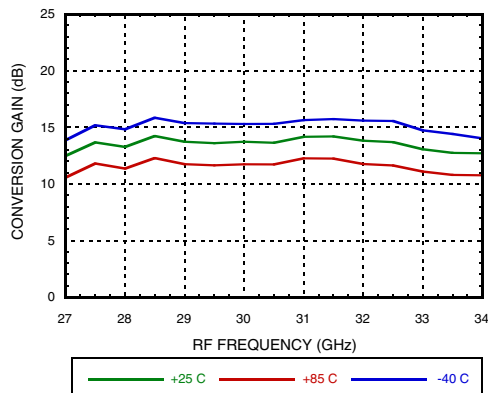
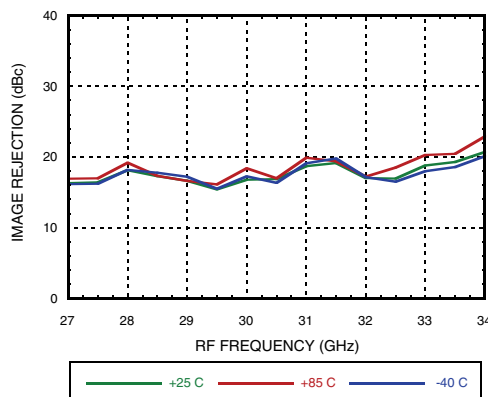
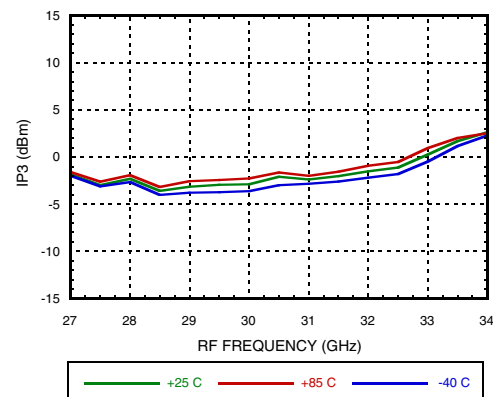


Image Rejection vs. Temperature, USB



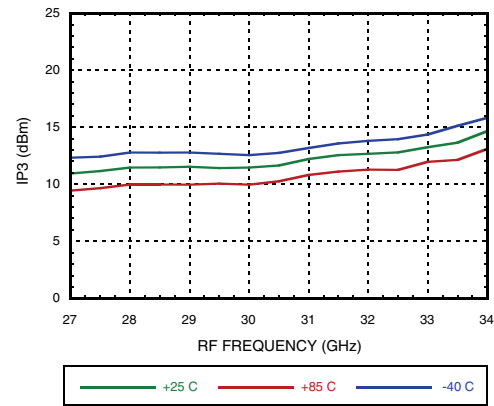
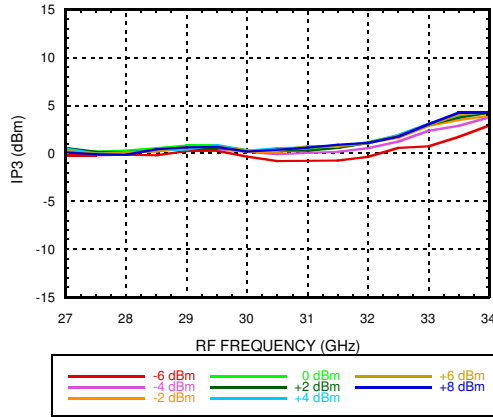
Input IP3 vs. Temperature, USB



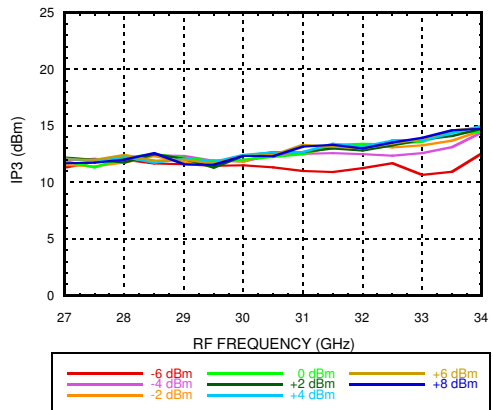


**GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz**

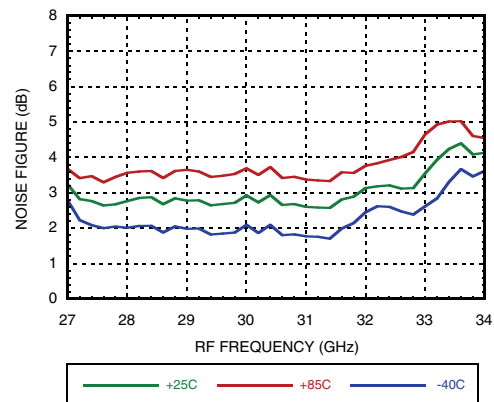
Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz
Input IP3 vs. LO Drive, USB **Output IP3 vs. Temperature, USB**



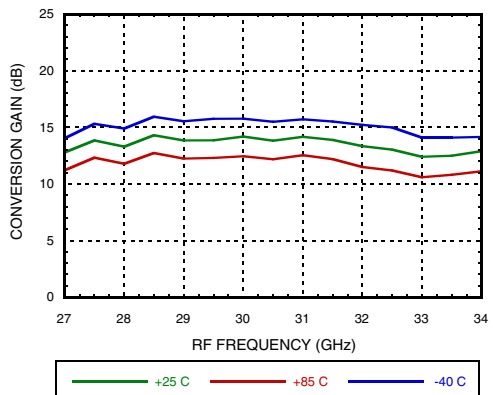
Output IP3 vs. LO Drive, USB



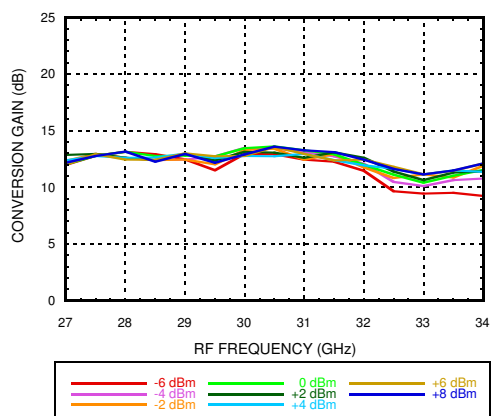
Noise Figure vs. Temperature, USB



Conversion Gain vs. Temperature, LSB



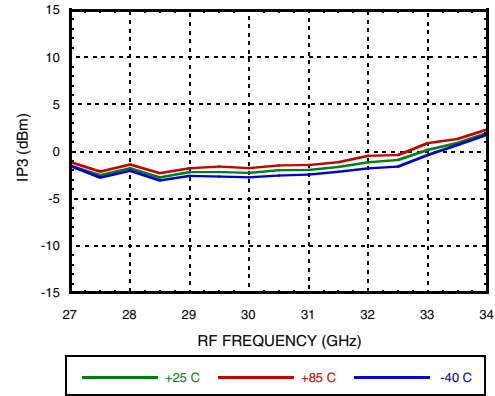
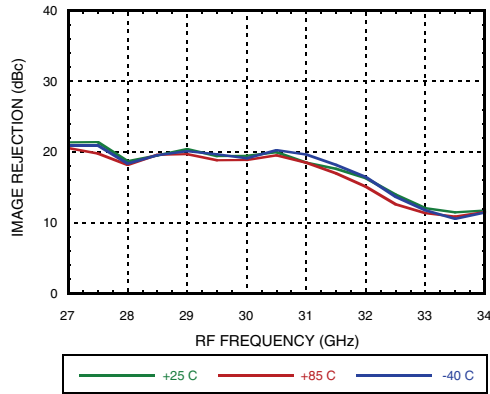
Conversion Gain vs. LO Drive, LSB



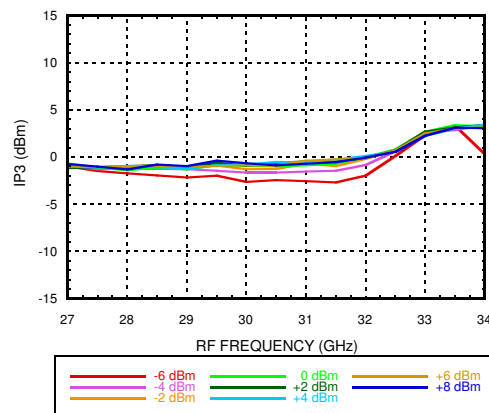


GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz

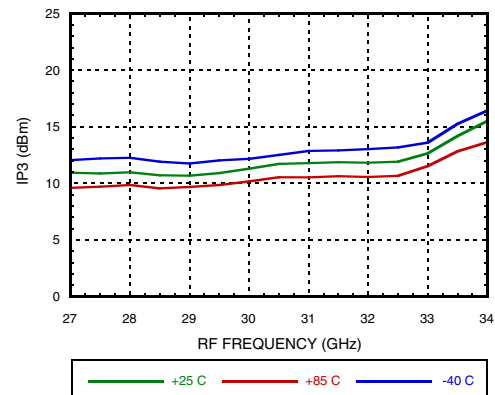
Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz
Image Rejection vs. Temperature, LSB **Input IP3 vs. Temperature, LSB**



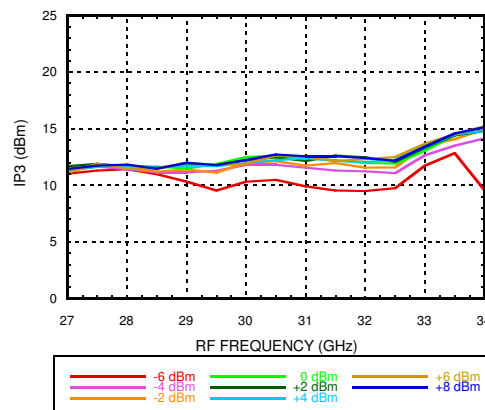
Input IP3 vs. LO Drive LSB



Output IP3 vs. Temperature, LSB



Output IP3 vs. LO Drive, LSB

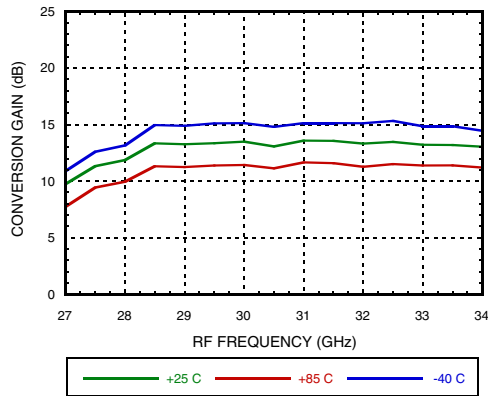




**GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz**

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3300 MHz

Conversion Gain vs. Temperature, USB



Conversion Gain vs. LO Drive, USB

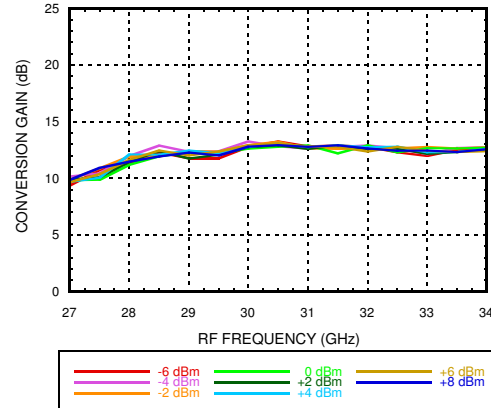
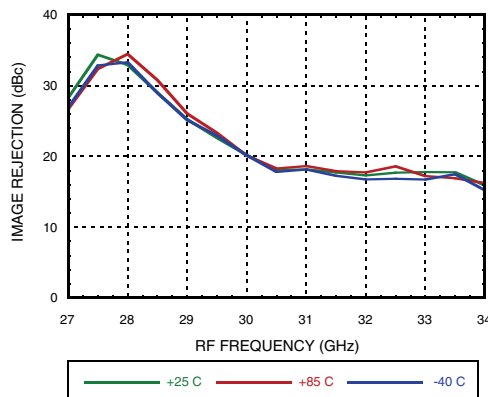
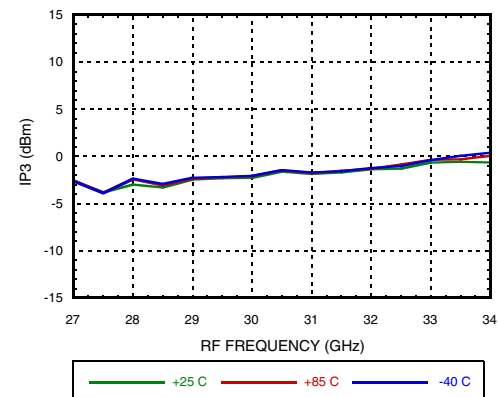


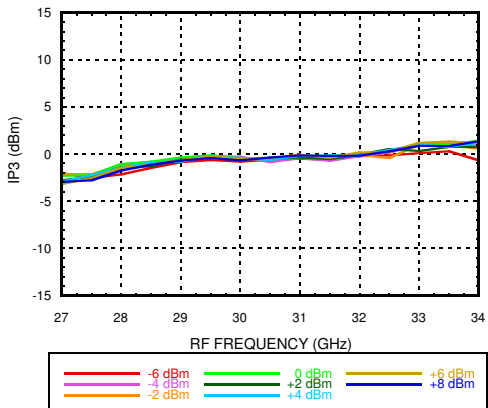
Image Rejection vs. Temperature, USB



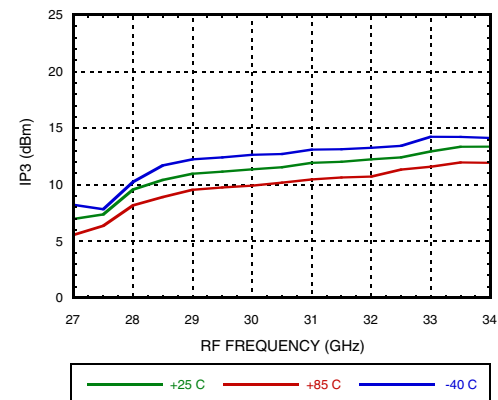
Input IP3 vs. Temperature, USB



Input IP3 vs. LO Drive, USB



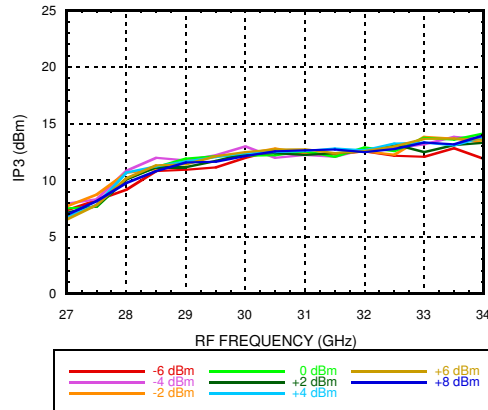
Output IP3 vs. Temperature, USB



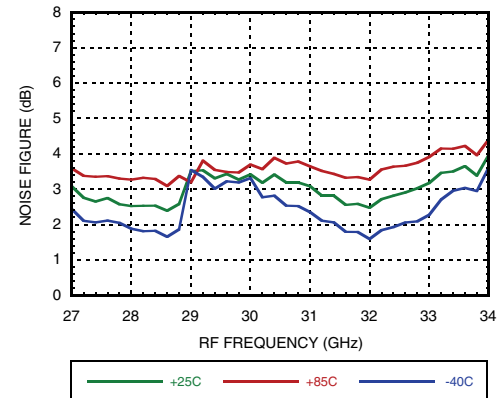


**GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz**

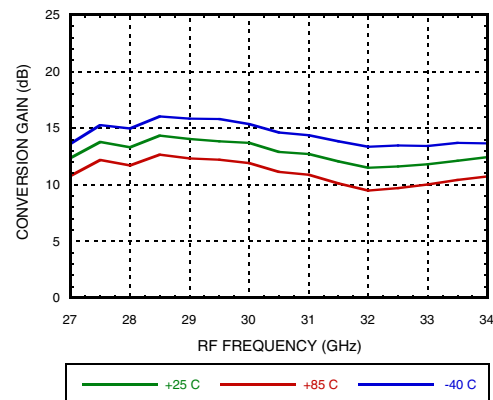
**Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3300 MHz
Output IP3 vs. LO Drive, USB**



Noise Figure vs. Temperature, USB



Conversion Gain vs. Temperature, LSB



Conversion Gain vs. LO Drive, LSB

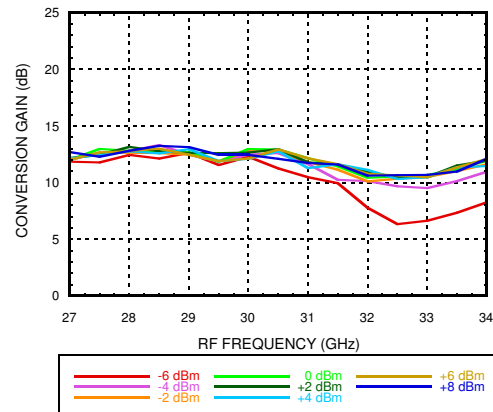
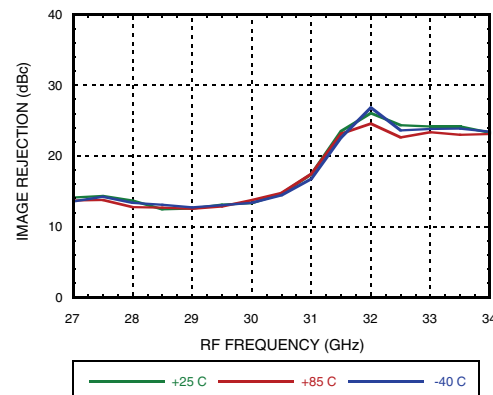
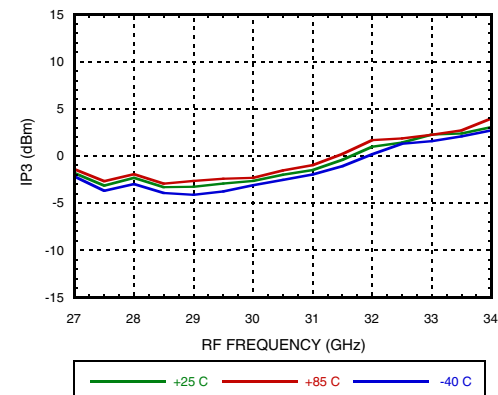


Image Rejection vs. Temperature, LSB

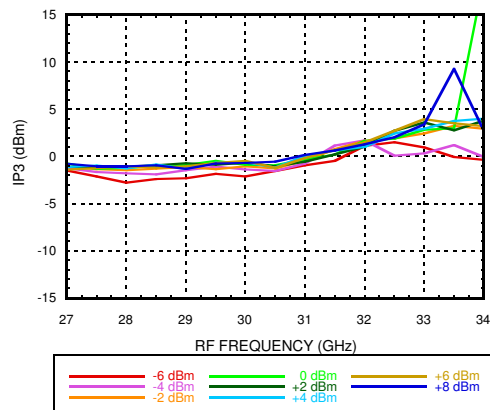
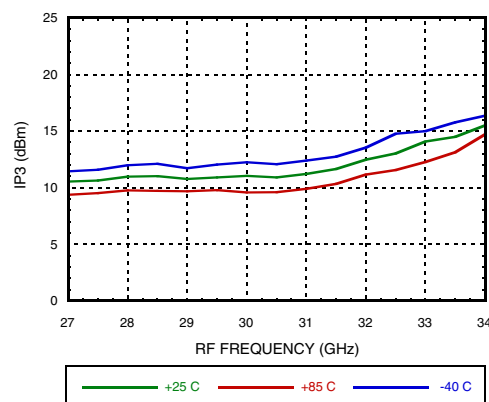
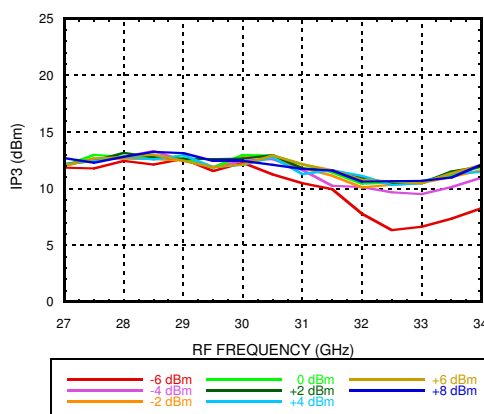


Input IP3 vs. Temperature, LSB




GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3300 MHz

Input IP3 vs. LO Drive, LSB

Output IP3 vs. Temperature, LSB

Output IP3 vs. LO Drive, LSB




GaAs MMIC I/Q DOWNCONVERTER

27 - 34 GHz

MxN Spurious Outputs, IF = 1 GHz ^[1]

mRF	nLO				
	0	1	2	3	4
0	x	35	18	49	
1	7	41	0	48	28
2		59	52	64	35
3				85	69

RF = 30 GHz @ -8 dBm

LO = 14.5 GHz @ +2 dBm

All values in dBc below IF power level (1RF -2LO)

Spur values are (M x RF) + (N x LO)

MxN Spurious Outputs, IF = 2 GHz ^[1]

mRF	nLO				
	0	1	2	3	4
0	x	32	18	52	
1	8	48	0	47	31
2		64	61	65	37
3				86	68

RF = 30 GHz @ -8 dBm

LO = 14.0 GHz @ +2 dBm

All values in dBc below IF power level (1RF -2LO)

Spur values are (M x RF) + (N x LO)

MxN Spurious Outputs, IF = 3.3 GHz ^[1]

mRF	nLO				
	0	1	2	3	4
0		42	23	46	
1	7	50	0	38	28
2		79	60	67	43
3				88	63

RF = 30 GHz @ -8 dBm

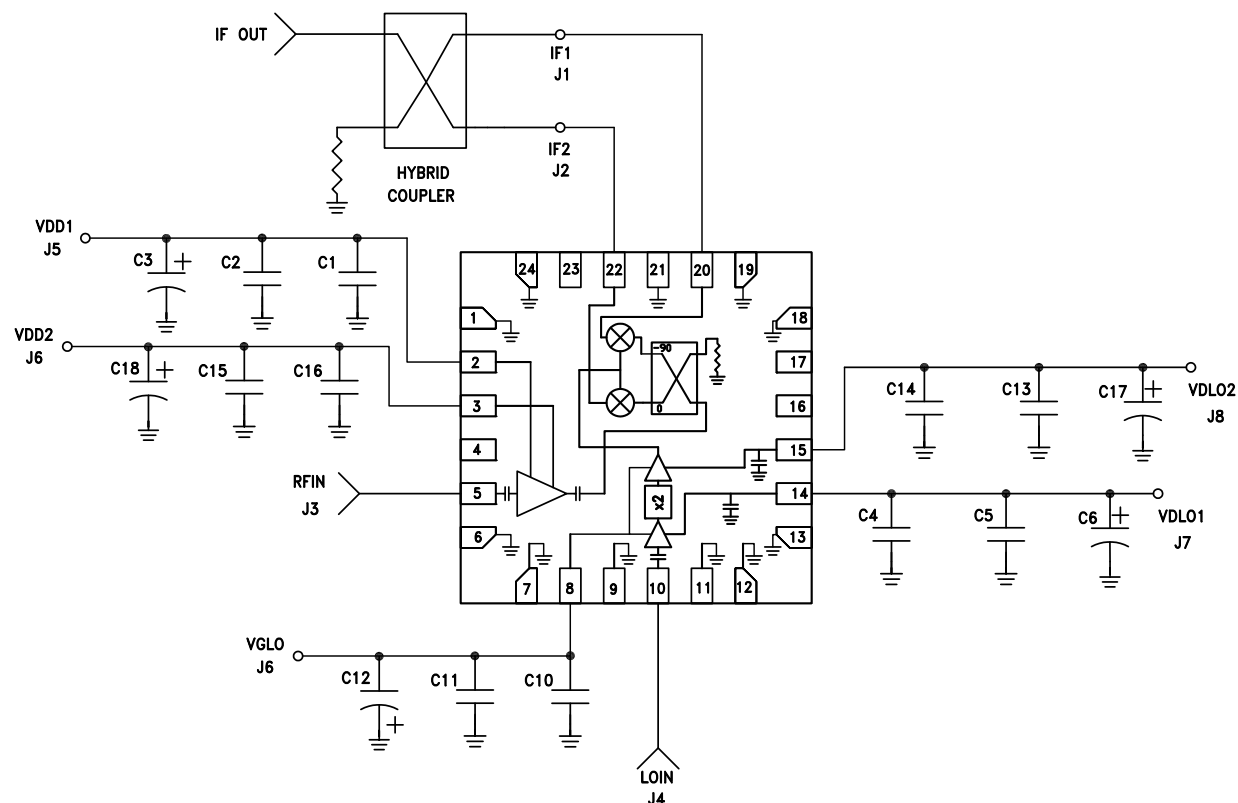
LO = 13.35 GHz @ +2 dBm

All values in dBc below IF power level (1RF -2LO)

Spur values are (M x RF) + (N x LO)


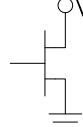
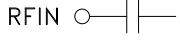
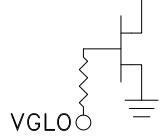
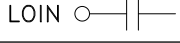
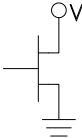
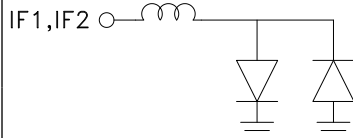
[1] Data taken without external IF 90° hybrid

Typical Application



C1, C4, C10, C14, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C11, C13, C15	0.1 uF Capacitor, 0402 Pkg.
C3, C6, C12, C17, C18	4.7 uF Capacitor, Case A Pkg.

**GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz**
Pin Descriptions

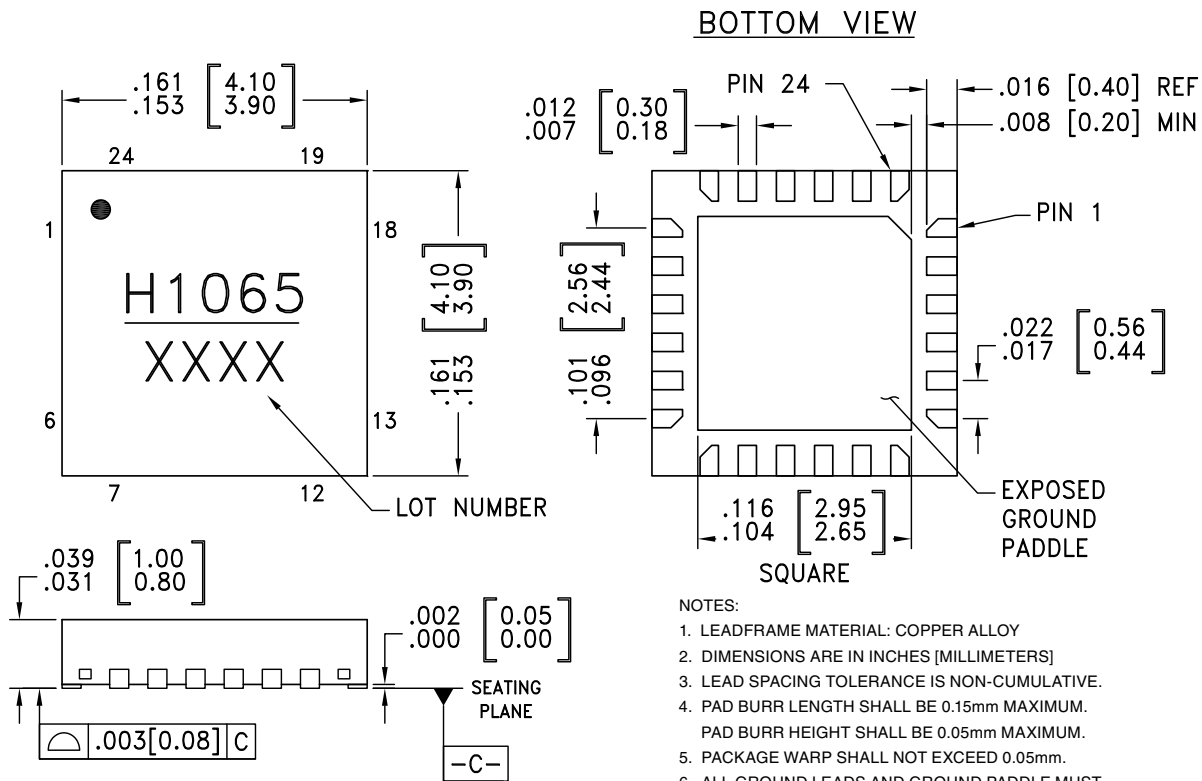
Pin Number	Function	Description	Interface Schematic
1, 4, 6, 7, 9, 11, 12, 13, 18, 19, 21, 24	GND	Ground Connect. These pins and exposed ground paddle must be connected to RF/DC ground.	
2	VDD1	Drain Bias for the low noise amplifier. The recommended DC voltage is 3 V. Refer to the typical application circuit for required external components.	
3	VDD2		
5	RFIN	Radio Frequency Input. This pin is AC coupled and matched to 50 Ohms.	
8	VGLO	Gate Bias for the Local Oscillator. Adjust VGLO from -2 V to 0 V to set total VDLO1 and VDLO2 current to 150mA. Refer to the typical application circuit for required external components.	
10	LOIN	Local Oscillator Input. This pin is AC coupled and matched to 50 Ohms.	
14	VDLO1	Drain Bias for the Multiplier Input Buffer Amp. The recommended DC voltage is 3V. Refer to the typical application circuit for required external components.	
15	VDLO2	Drain Bias for the Multiplier output Buffer Amp. The recommended DC voltage is 3V. Refer to the typical application circuit for required external components.	
16, 17, 23	N/C	No connection required. The pins are not connected internally. However, all data shown herein was measured with these pins connected to RF/DC ground externally.	
20	IF1	Quadrature Intermediate Frequency Inputs. These pins are DC coupled. For applications not requiring operation to DC, use an off chip DC blocking capacitor. For operation to DC, these pins must not source/sink more than 3 mA of current or device non-function and failure may result.	
22	IF2		


GaAs MMIC I/Q DOWNCONVERTER
27 - 34 GHz
Absolute Maximum Ratings

RF Input	+8 dBm
LO Input	+8 dBm
Drain Bias Voltage (Vdd)	+3.5 V
Channel Temperature	175 °C
Continuous P _{diss} (T = 85°C) (derate 18.5 mW/°C above 85°C)	1.66 W
Thermal Resistance (channel to ground paddle)	54.1 °C/W
Storage Temperature Range	-65 to +150 °C
Operating Temperature Range	-40 to +85 °C
ESD Sensitivity (HBM)	250 V (Class 1A)



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

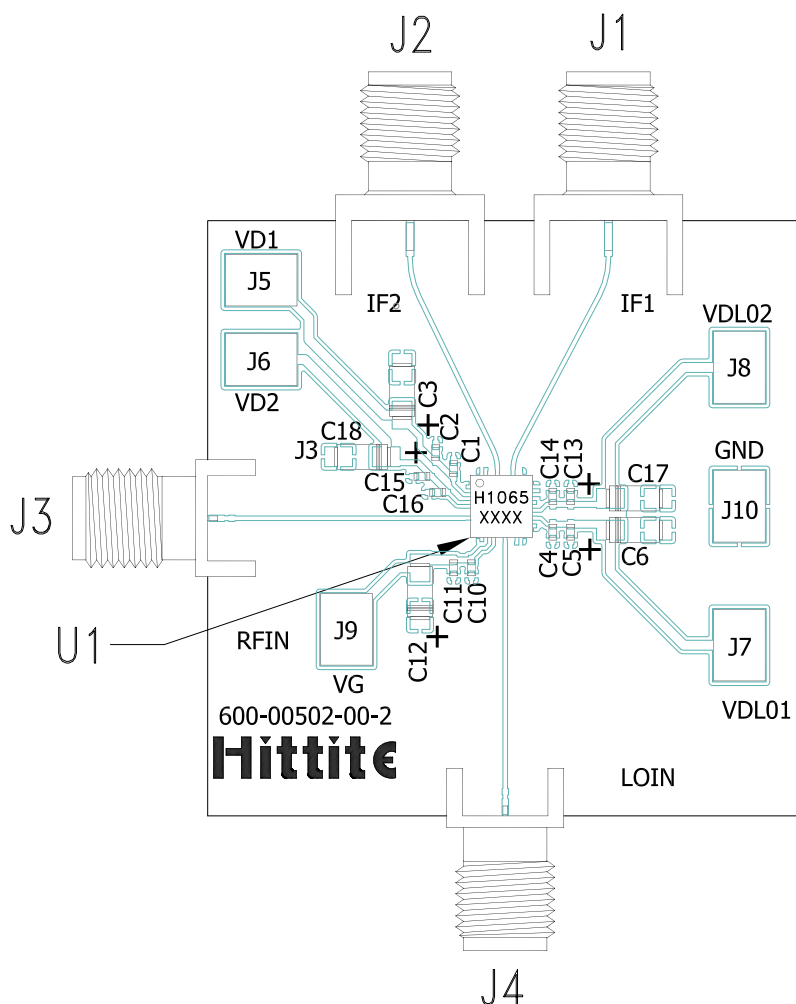
Outline Drawing

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC1065LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% Sn 10 micron min	MSL1 ^[1]	H1065 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

Evaluation PCB



List of Materials for Evaluation PCB Eval01-HMC1065LP4 [1]

Item	Description
J1, J2	SMA SRI
J3, J4	K-Connector SRI
J5 - J10	DC Pins
C1, C4, C10, C14, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C11, C13, C15	0.1 uF Capacitor, 0402 Pkg.
C3, C6, C12, C17, C18	4.7 uF Capacitor, Case A
U1	HMC1065LP4E Downconverter
PCB [2]	600-00502-00 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR, FR4 or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Analog Devices upon request.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

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- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
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- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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